

### Product Summary

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	$I_D$
-30V	50mΩ@-10V	-4.2A
	60mΩ@-4.5V	
	85mΩ@-2.5V	

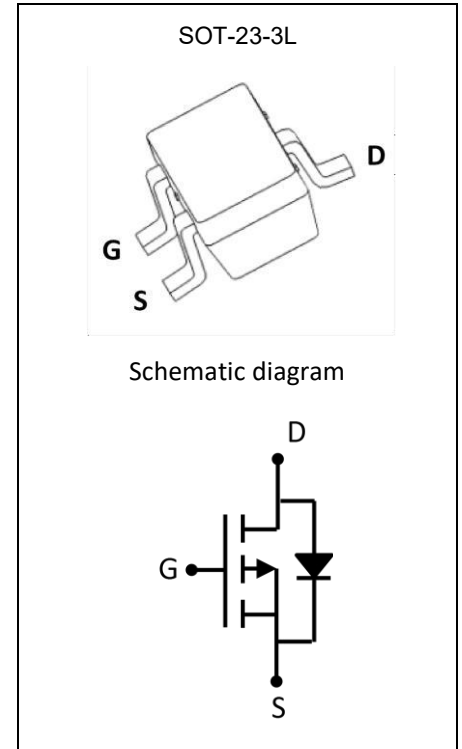
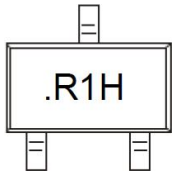
### Feature

- TrenchFET Power MOSFET
- Exceptional on-resistance and maximum DC current capability

### Application

- DC/DC Converter
- Load Switch for Portable Devices
- Battery Switch

### MARKING:



### ABSOLUTE MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	-30	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	V
Continuous Drain Current	$I_D$	-4.2	A
Power Dissipation	$P_D$	0.45	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	277	$^\circ\text{C}/\text{W}$
Junction Temperature	$T_J$	150	$^\circ\text{C}$
Storage Temperature	$T_{STG}$	-55~+150	$^\circ\text{C}$

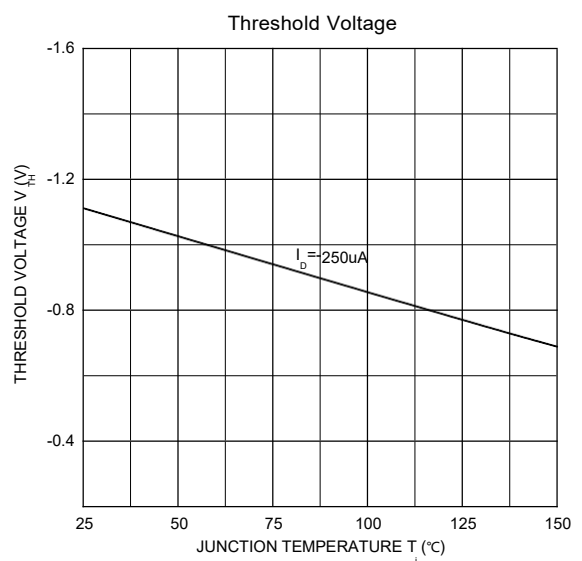
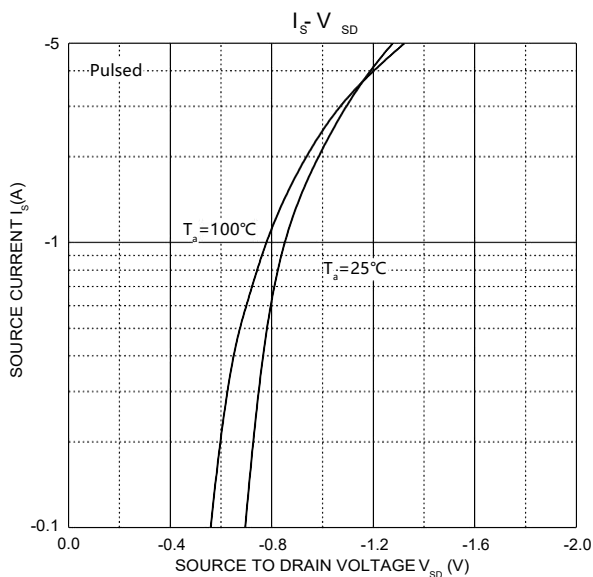
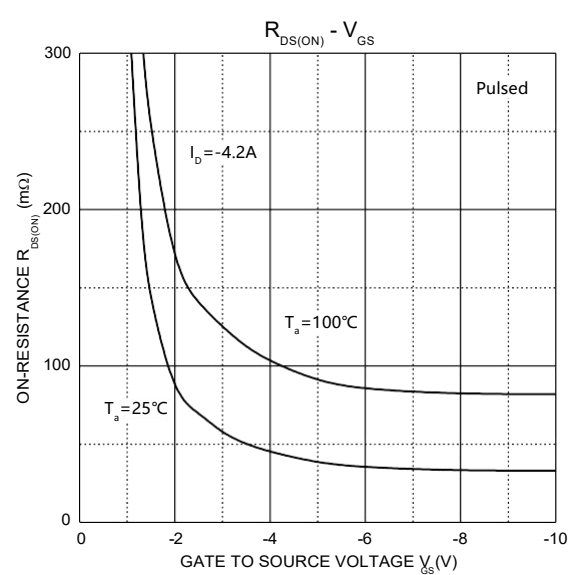
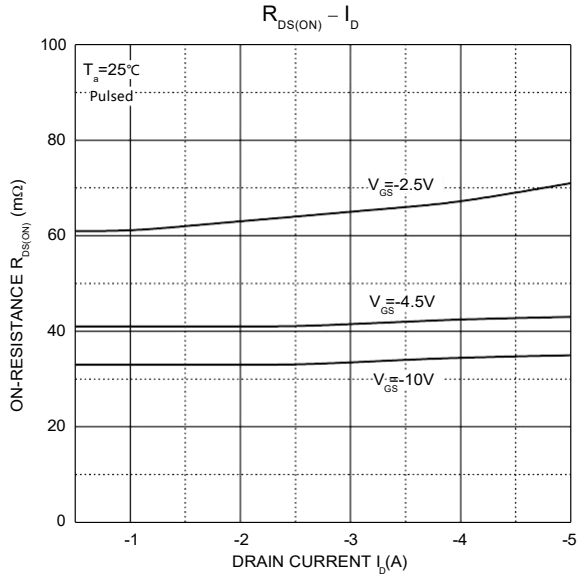
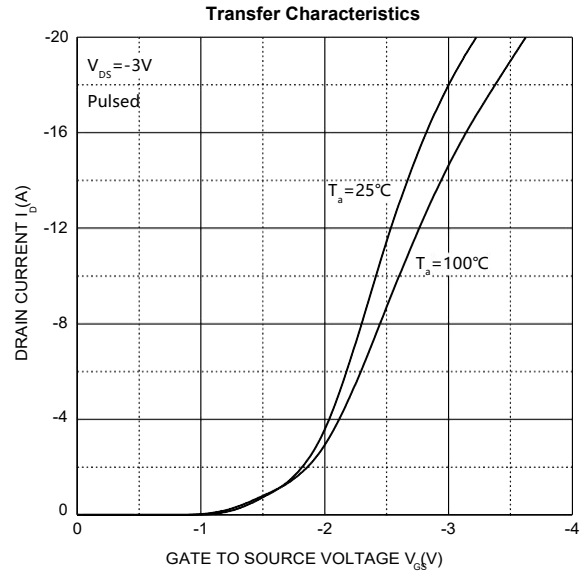
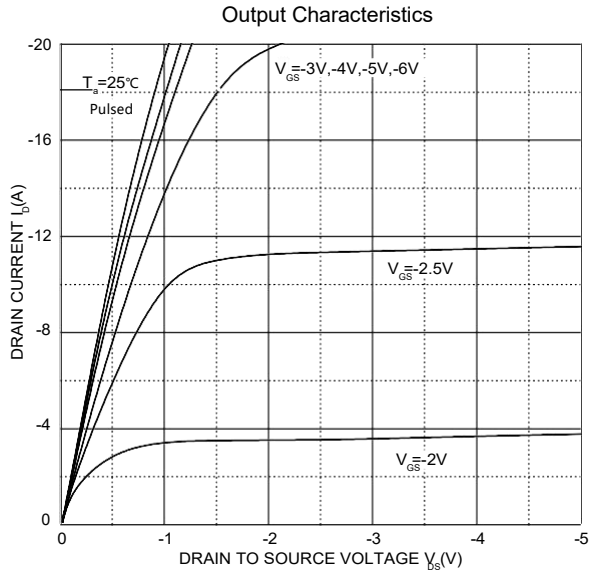
**MOSFET ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$  unless otherwise noted)**

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
<b>Static Characteristics</b>						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-30			V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = -24V, V_{GS} = 0V$			-1	$\mu A$
Gate-body leakage current	$I_{GSS}$	$V_{GS} = \pm 12V, V_{DS} = 0V$			100	nA
Gate threshold voltage <sup>(1)</sup>	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-0.7	-1.0	-1.3	V
Drain-source on-resistance <sup>(1)</sup>	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -4.0A$		40	50	m $\Omega$
		$V_{GS} = -4.5V, I_D = -3.5A$		46	60	
		$V_{GS} = -2.5V, I_D = -2.5A$		58	85	
Forward transconductance	$g_{FS}$	$V_{DS} = -5V, I_D = -5A$	7			S
<b>Dynamic characteristics<sup>(2)</sup></b>						
Input Capacitance	$C_{iss}$	$V_{DS} = -15V, V_{GS} = 0V, f = 1MHz$		1050		pF
Output Capacitance	$C_{oss}$			127		
Reverse Transfer Capacitance	$C_{rss}$			85		
<b>Switching characteristics<sup>(2)</sup></b>						
Turn-on delay time	$t_{d(on)}$	$V_{GS} = -10V, V_{DS} = -15V,$ $R_L = 3.6\Omega, R_{GEN} = 6\Omega$			6.5	ns
Turn-on rise time	$t_r$				3.5	
Turn-off delay time	$t_{d(off)}$				40	
Turn-off fall time	$t_f$				13	
<b>Source-Drain Diode characteristics</b>						
Diode Forward voltage <sup>(1)</sup>	$V_{DS}$	$V_{GS} = 0V, I_S = -1A$			-1	V

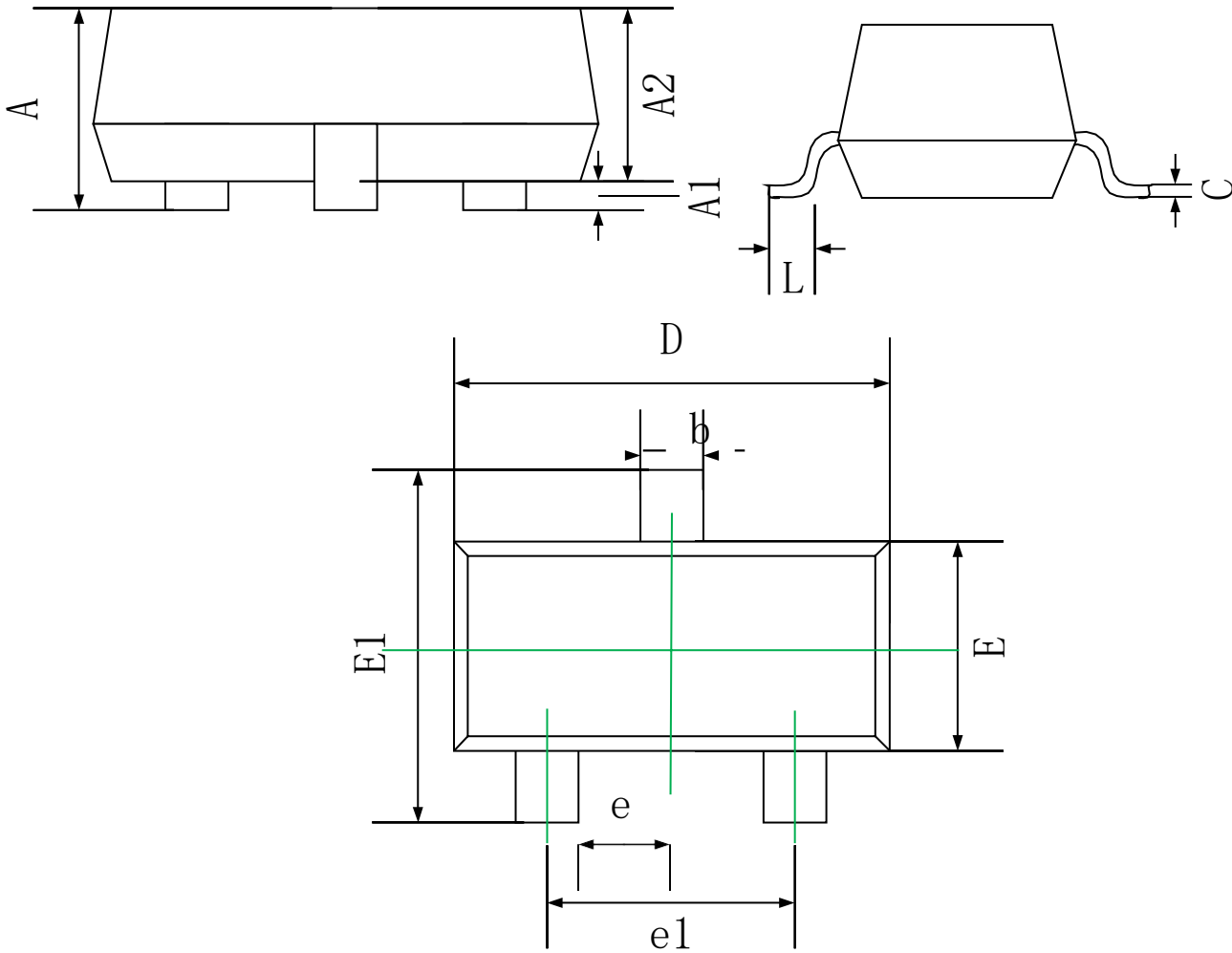
**Notes:**

1. Pulse test; pulse width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$ .
2. Guaranteed by design, not subject to production testing.

## Typical Electrical and Thermal Characteristics



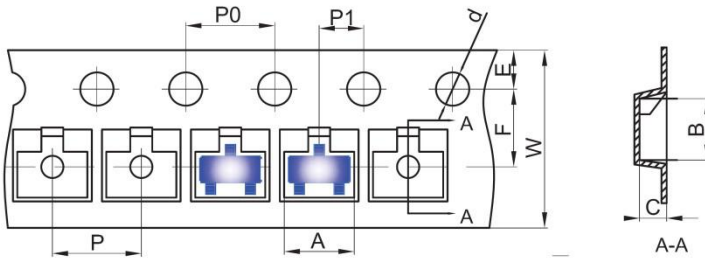
SOT-23-3L Package Information



Symbol	Dimensions In Millimeters	
	Min.	Max.
A	1.05	1.25
A1	0.00	0.10
A2	1.05	1.15
b	0.30	0.50
c	0.10	0.20
D	2.82	3.02
E	1.50	1.70
E1	2.65	2.95
e	0.95 REF.	
e1	1.80	2.00
L	0.30	0.50

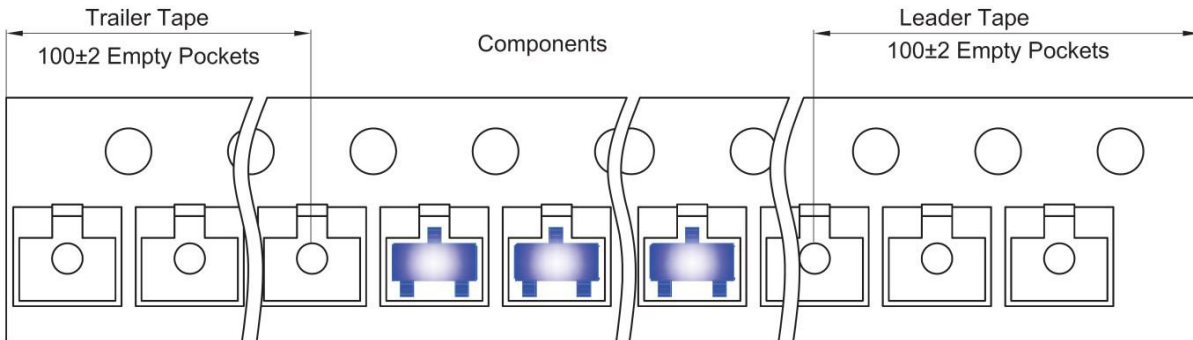
SOT-23 Tape and Reel

SOT-23-3L Embossed Carrier Tape

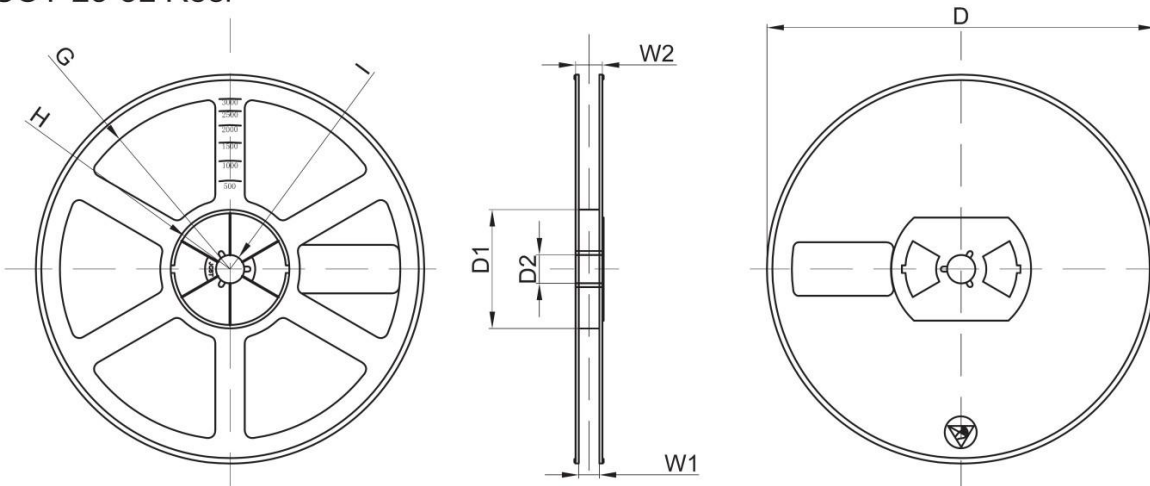


Dimensions are in millimeter											
Pkg type	A	B	C	d	E	F	P0	P	P1	W	
SOT-23-3L	3.18	3.28	1.32	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00	

SOT-23-3L Tape Leader and Trailer



SOT-23-3L Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø180.00	60.00	13.00	R78.00	R25.60	R6.50	9.50	13.10

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	